TOSHIBA Field Effect Transistor Silicon N Channel MOS Type ( $L^2-\pi$ -MOSV)

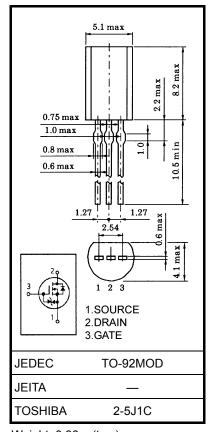
# 2SK2961

Relay Drive, Motor Drive and DC–DC Converter Application

- Low drain-source ON resistance :  $R_{DS (ON)} = 0.2 \Omega$  (typ.)
- High forward transfer admittance : |Y<sub>fs</sub>| = 2.0 S (typ.)
- Low leakage current : I<sub>DSS</sub> = 100 μA (max) (V<sub>DS</sub> = 60 V)
- Enhancement mode :  $V_{th} = 0.8$  to 2.0 V ( $V_{DS} = 10$  V,  $I_D = 1$  mA)

#### Absolute Maximum Ratings (Ta = 25°C)

| Characteristics                              |                | Symbol           | Rating     | Unit |  |
|--|----------------|------------------|------------|------|--|
| Drain-source voltage                         |                | V <sub>DSS</sub> | 60         | V    |  |
| Drain-gate voltage (R <sub>GS</sub> = 20 kΩ) |                | V <sub>DGR</sub> | 60         | V    |  |
| Gate-source voltage                          |                | V <sub>GSS</sub> | ±20        | V    |  |
| Drain current                                | DC (Note 1)    | ۱ <sub>D</sub>   | 2.0        | А    |  |
|  | Pulse (Note 1) | I <sub>DP</sub>  | 6.0        | 4    |  |
| Drain power dissipation                      |                | PD               | 0.9        | W    |  |
| Channel temperature                          |                | T <sub>ch</sub>  | 150        | °C   |  |
| Storage temperature range                    |                | T <sub>stg</sub> | -55 to 150 | °C   |  |



Weight: 0.36 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

| Characteristics                        | Symbol                 | Max | Unit   |  |
|--|------------------------|-----|--------|--|
| Thermal resistance, channel to ambient | R <sub>th (ch−a)</sub> | 138 | °C / W |  |

Note 1: Ensure that the channel temperature does not exceed 150°C.

This transistor is an electrostatic-sensitive device. Please handle with caution.

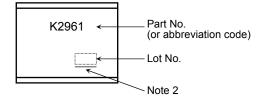
**Electrical Characteristics (Ta = 25°C)** 

| Charac  | cteristics      | Symbol                | Test Condition   | Min | Тур. | Max  | Unit |
|---|-----------------|-----------------------|--|-----|------|------|------|
| Gate leakage cu                                 | irrent          | I <sub>GSS</sub>      | V <sub>GS</sub> = ±16 V, V <sub>DS</sub> = 0 V   |     | _    | ±10  | μA   |
| Drain cut-off cu                                | rrent           | I <sub>DSS</sub>      | V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0 V  | _   | _    | 100  | μA   |
| Drain-source br                                 | eakdown voltage | V <sub>(BR)</sub> DSS | I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V  | 60  | _    | _    | V    |
| Gate threshold v                                | voltage         | V <sub>th</sub>       | V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA  | 0.8 | _    | 2.0  | V    |
| Drain-source ON resistance                      |                 | R <sub>DS (ON)</sub>  | V <sub>GS</sub> = 4 V, I <sub>D</sub> = 1.0 A  |     | 0.26 | 0.38 | Ω    |
|   |                 | 00 (011)              | V <sub>GS</sub> = 10 V, I <sub>D</sub> = 1.0 A   | —   | 0.20 | 0.27 |      |
| Forward transfer                                | r admittance    | Y <sub>fs</sub>       | V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1.0 A   | 1.0 | 2.0  | —    | S    |
| Input capacitance                               | e               | C <sub>iss</sub>      |  |     | 170  | —    | pF   |
| Reverse transfer capacitance                    |                 | C <sub>rss</sub>      | V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz   | _   | 25   | _    |      |
| Output capacitance                              |                 | Coss                  |  |     | 75   | _    |      |
| Switching time                                  | Rise time       | tr                    | $V_{GS} \xrightarrow{10V}_{0V} \int_{\mathbb{C}} \xrightarrow{I_D=1A}_{0V} V_{OUT}$ $R_L=30\Omega$ $V_{DD}=30V$ $Duty \leq 1\%, t_w=10\mu s$ | _   | 10   | _    |      |
|   | Turn-on time    | t <sub>on</sub>       |  | _   | 15   | _    | ns   |
|   | Fall time       | t <sub>f</sub>        |  |     | 50   | —    | 115  |
|   | Turn-off time   | t <sub>off</sub>      |  | -   | 170  | —    |      |
| Total gate charge (gate-source plus gate-drain) |                 | Qg                    |  | _   | 5.8  | _    |      |
| Gate-source charge                              |                 | Q <sub>gs</sub>       | V <sub>DD</sub> ≈ 48 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 2 A   | _   | 4.1  | _    | nC   |
| Gate-drain ("miller") Charge                    |                 | Q <sub>gd</sub>       | ] /  |     | 1.7  | —    |      |

#### Source–Drain Ratings and Characteristics (Ta = 25°C)

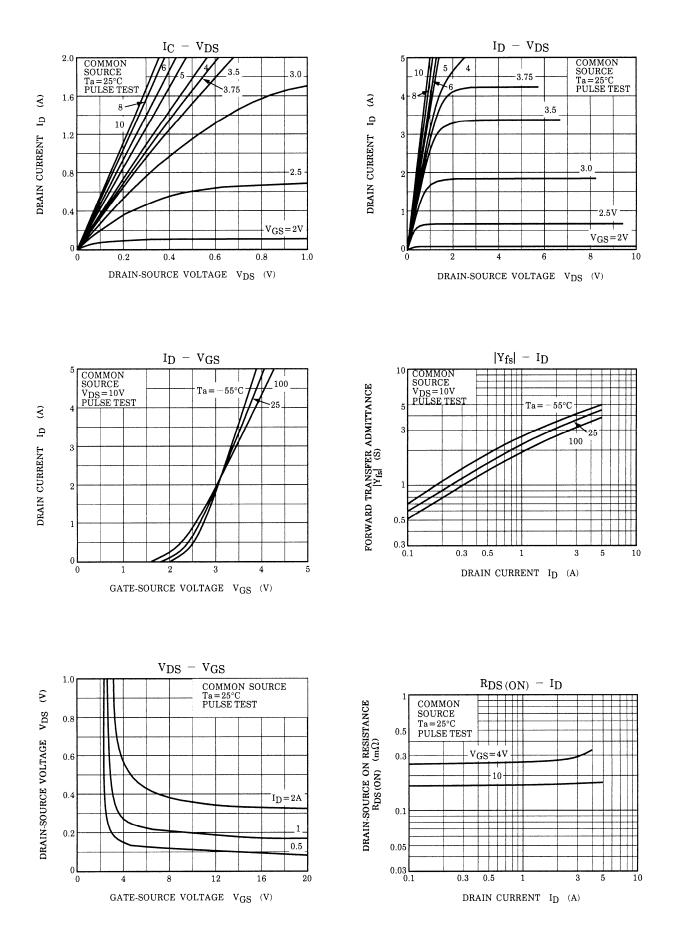
| Characteristics                              | Symbol           | Test Condition  | Min | Тур. | Max  | Unit |
|--|------------------|---|-----|------|------|------|
| Continuous drain reverse<br>current (Note 1) | I <sub>DR</sub>  | -   | _   | _    | 2.0  | A    |
| Pulse drain reverse current<br>(Note 1)      | I <sub>DRP</sub> | _   |     |      | 6.0  | A    |
| Forward voltage (diode)                      | V <sub>DSF</sub> | I <sub>DR</sub> = 2 A, V <sub>GS</sub> = 0 V                                    | -   | -    | -1.5 | V    |
| Reverse recovery time                        | t <sub>rr</sub>  | I <sub>DR</sub> = 2 A, V <sub>GS</sub> = 0 V, dI <sub>DR</sub> / dt = 50 A / μs |     | 45   |      | ns   |
| Reverse recovery charge                      | Q <sub>rr</sub>  | $10R = 2 R$ , $v_{GS} = 0 v$ , $00R / 01 = 50 R / \mu s$                        | _   | 40.5 | _    | nC   |

### Marking

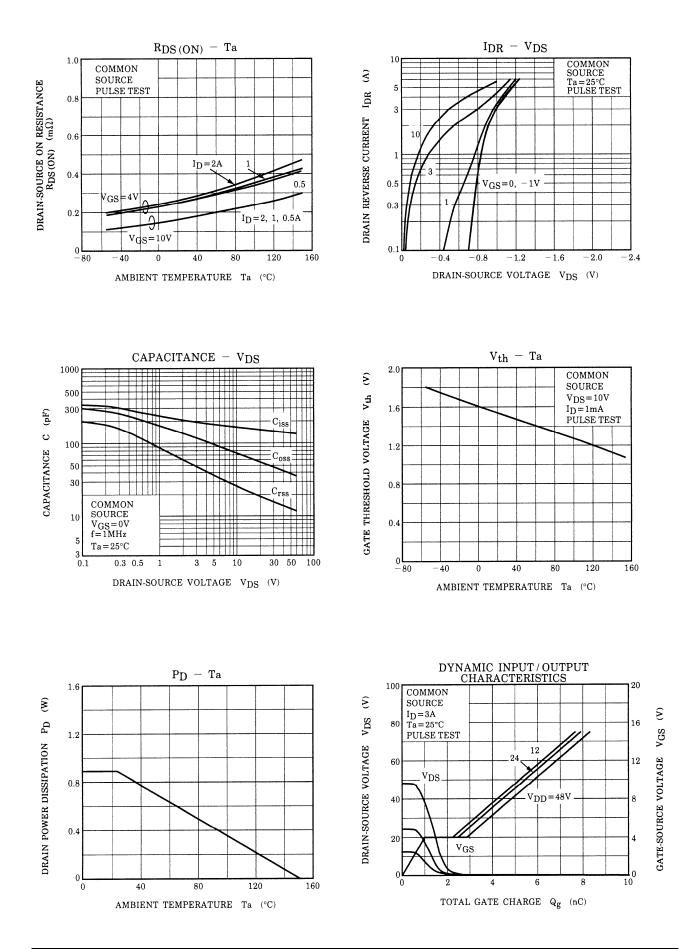


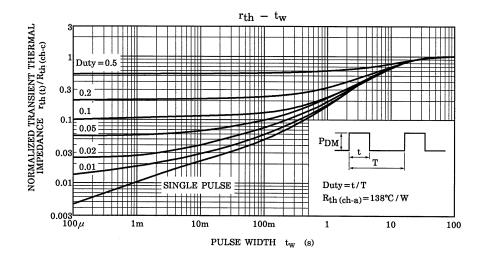
Note 2: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

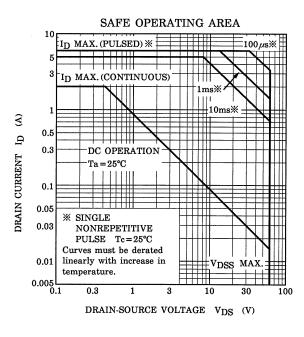
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